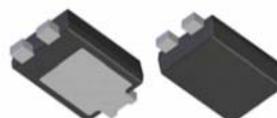


Features

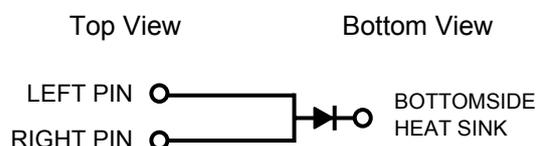
- High current capability, low forward voltage
- Excellent high temperature stability
- Low power loss, and high efficiency
- High Forward Surge Capability
- Patented package technology

TO-277B (SMD)



Applications

- Switching mode power supply applications
- Portable equipment battery applications
- High frequency rectification
- DC/DC Converter
- Designed as bypass diodes for solar panels



ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive peak reverse voltage	V_{RRM}	50	V
Maximum DC blocking voltage	V_{RM}	50	
Average forward current	$I_{F(AV)}$	15	A
Surge non repetitive forward current (8.3ms single half sine- wave)	I_{FSM}	295	
Single pulse davalanche energy ($I_{AS}=12\text{A}$, $L=10\text{mH}$)	E_{AS}	530	mJ
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55~+150	
Thermal Resistance, Junction-to-Ambiene	R_{QJA}	73	$^{\circ}\text{C/W}$
	R_{QJA}	31	

Note: 1. FR-4 PCB, 2oz. Copper.

2. Polyimide PCB, 2oz. Copper. Cathode pad dimensions 18.8mm \times 14.4mm. Anode pad dimensions 5.6mm \times 14.4mm.

Electrical Characteristics

Characteristic	Symbol	Test Condition	Rating			UNIT	
			Min	Typ	Max		
Forward voltage drop	V_F	$I_F=3\text{A}$	--	0.33	0.36	V	
			$I_F=10\text{A}$	--	0.41		0.46
		$I_F=15\text{A}$		$T_J=25^{\circ}\text{C}$	--		0.43
			$T_J=100^{\circ}\text{C}$	--	0.40		0.41
Reverse leakage current	I_R	$V_R=\text{Max. } V_{RRM}$	$T_J=25^{\circ}\text{C}$	--	0.076	0.30	mA
			$T_J=125^{\circ}\text{C}$	--	16	60	



Fig-1. Typical Forward Characteristics

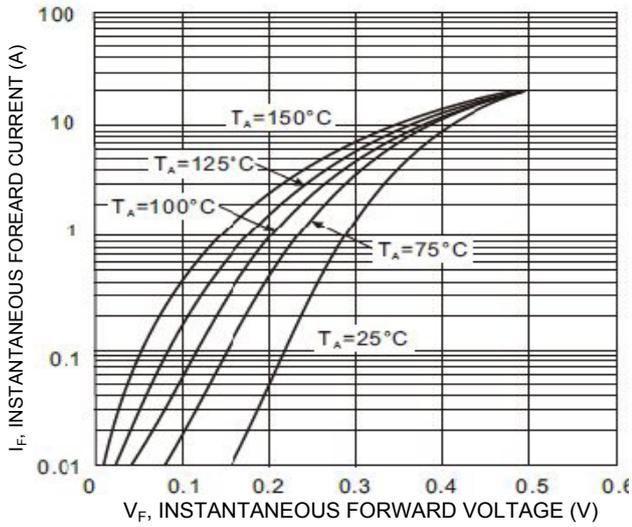


Fig-2. Typical Reverse Characteristics

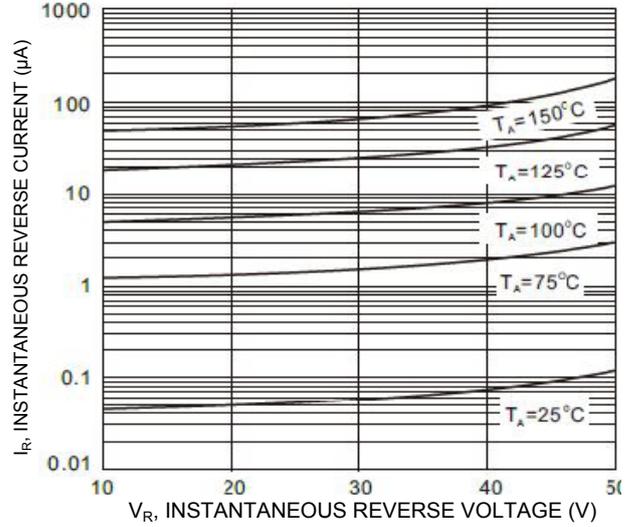


Fig-3. Forward Current Derating Curve

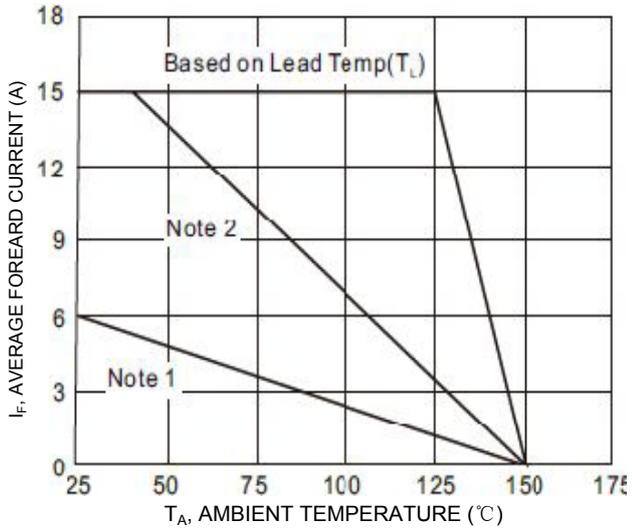


Fig-4. Operating Temperature Derating Curve

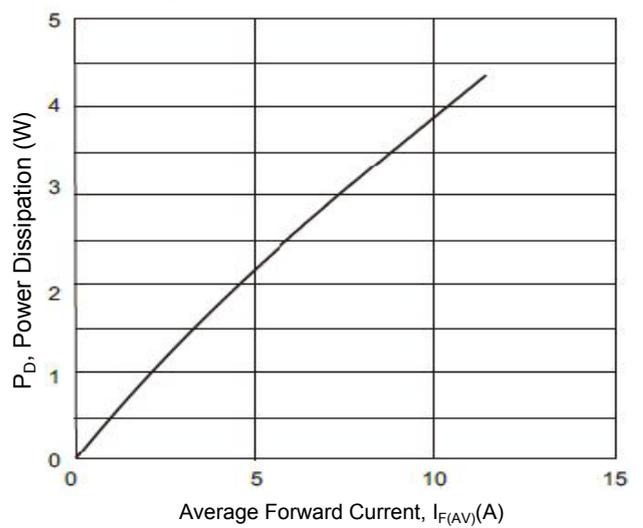


Fig-5. Total Capacitance VS. Reverse Voltage

